

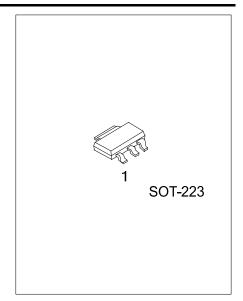
## UNISONIC TECHNOLOGIES CO., LTD

04NM50 Preliminary Power MOSFET

# 0.4A, 500V N-CHANNEL SUPER-JUNCTION MOSFET

#### **■** DESCRIPTION

The UTC **04NM50** is an Super Junction MOSFET Structure and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.



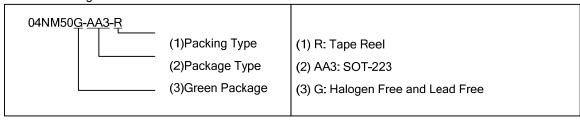
#### ■ FEATURES

- \*  $R_{DS(on)}$  < 12 $\Omega$  @  $V_{GS}$ =10V,  $I_{D}$ =0.2A
- \* High breakdown voltage

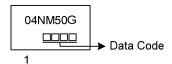
#### **■ ORDERING INFORMATION**

Ordering Number	Package	Pin Assignment			Dooking	
		1	2	3	Packing	
04NM50G-AA3-R	SOT-223	G	D	S	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



#### **■** MARKING



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## ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>C</sub> =25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	500	V
Gate-Source Voltage		$V_{GSS}$	±30	V
Drain Current	Continuous	I <sub>D</sub>	0.4	Α
	Pulsed	I <sub>DM</sub>	1.6	Α
Power Dissipation		P <sub>D</sub>	9	W
Junction Temperature		TJ	150	°C
Storage Temperature Range		T <sub>STG</sub>	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## **■ THERMAL DATA**

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	$\theta_{JA}$	θ <sub>JA</sub> 150		
Junction to Case	$\theta_{JC}$	14	°C/W	

## ■ ELECTRICAL CHARACTERISTICS (T<sub>C</sub> =25°C, unless otherwise specified)

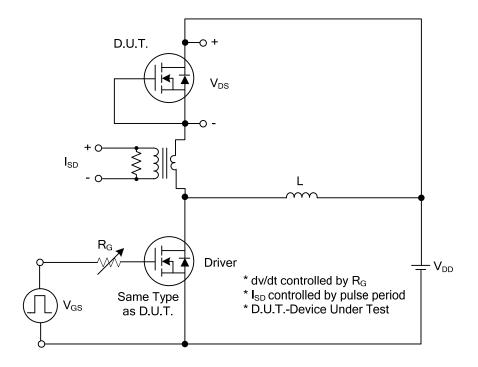
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		$BV_DSS$	$I_D=250\mu A, V_{GS}=0V$				٧
Drain-Source Leakage Current		$I_{DSS}$	V <sub>DS</sub> =500V, V <sub>GS</sub> =0V			10	μΑ
Gate-Source Leakage Current	Forward	- I <sub>GSS</sub>	$V_{GS}$ =+30V, $V_{DS}$ =0V			+100	nΑ
	Reverse		$V_{GS}$ =-30V, $V_{DS}$ =0V			-100	nΑ
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.5		4.5	٧
Static Drain-Source On-State Resistance		R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.2A			12	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C <sub>ISS</sub>			30		pF
Output Capacitance Reverse Transfer Capacitance		Coss	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1.0MHz		25		рF
		$C_{RSS}$			7.5		pF
SWITCHING PARAMETERS							
Total Gate Charge		$Q_G$	V -50V V -40V I -4.2A		8		nC
Gate to Source Charge		$Q_GS$	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.3A,		2.5		nC
Gate to Drain Charge		$Q_GD$	-I <sub>D</sub> =100μA (Note 1, 2)		3		nC
		$t_{D(ON)}$			38		ns
		t <sub>R</sub>	$V_{DS}$ =30V, $V_{GS}$ =10V, $I_{D}$ =0.5A, $R_{G}$ =25 $\Omega$ (Note 1, 2)		23		ns
		t <sub>D(OFF)</sub>			26		ns
					30		ns
SOURCE- DRAIN DIODE RATING	S AND CI	HARACTERI	STICS				
Maximum Body-Diode Continuous Current		Is				0.4	Α
Maximum Body-Diode Pulsed Current		I <sub>SM</sub>				1.6	Α
Drain-Source Diode Forward Voltage		$V_{SD}$	I <sub>S</sub> =0.4A, V <sub>GS</sub> =0V			1.4	V

Notes: 1. Pulse Test: Pulse width  $\leq$  300 $\mu$ s, Duty cycle  $\leq$  2%.

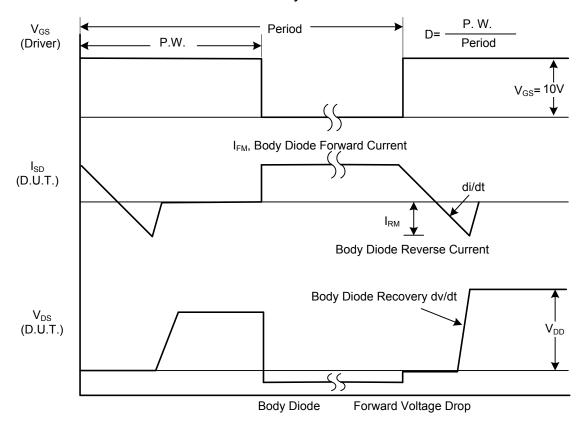
<sup>2.</sup> Repetitive Rating : Pulse width limited by maximum junction temperature.

<sup>2.</sup> Essentially independent of operating temperature.

#### **■ TEST CIRCUITS AND WAVEFORMS**

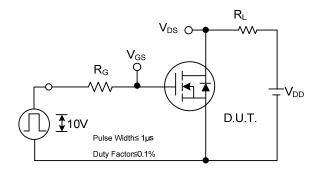


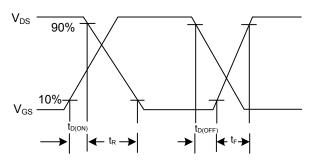
#### Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

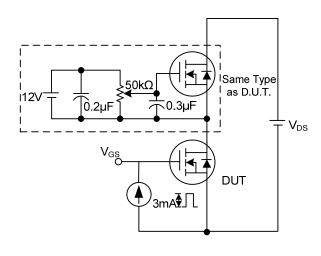
## ■ TEST CIRCUITS AND WAVEFORMS (Cont.)

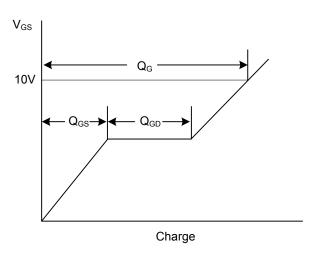




**Switching Test Circuit** 

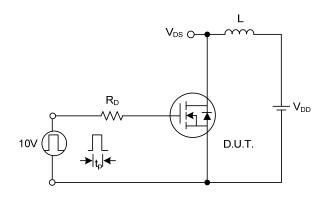
**Switching Waveforms** 

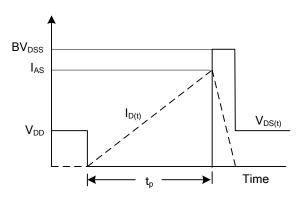




**Gate Charge Test Circuit** 

**Gate Charge Waveform** 





**Unclamped Inductive Switching Test Circuit** 

**Unclamped Inductive Switching Waveforms** 

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